# **General Purpose Transistor**

## **PNP Silicon**

This transistor is designed for general purpose amplifier applications. It is housed in the SOT-723 which is designed for low power surface mount applications.

#### **Features**

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### **MAXIMUM RATINGS**

| Rating                         | Symbol           | Value | Unit |
|--------------------------------|------------------|-------|------|
| Collector-Emitter Voltage      | V <sub>CEO</sub> | -65   | V    |
| Collector-Base Voltage         | V <sub>CBO</sub> | -80   | V    |
| Emitter-Base Voltage           | V <sub>EBO</sub> | -5.0  | V    |
| Collector Current – Continuous | I <sub>C</sub>   | -100  | mA   |

#### THERMAL CHARACTERISTICS

| Characteristic  | Symbol                            | Max            | Unit  |
|---|-----------------------------------|----------------|-------|
| Total Device Dissipation FR-5 Board<br>(Note 1)<br>T <sub>A</sub> = 25°C  | P <sub>D</sub>                    | 265            | mW    |
| Derate above 25°C   |                                   | 2.1            | mW/°C |
| Thermal Resistance,<br>Junction to Ambient (Note 1)                       | $R_{	hetaJA}$                     | 470            | °C/W  |
| Total Device Dissipation Alumina Substrate (Note 2) T <sub>A</sub> = 25°C | P <sub>D</sub>                    | 640            | mW    |
| Derate above 25°C   |                                   | 5.1            | mW/°C |
| Thermal Resistance, Junction to Ambient (Note 2)                          | $R_{	heta JA}$                    | 195            | °C/W  |
| Junction and Storage<br>Temperature Range                                 | T <sub>J</sub> , T <sub>stg</sub> | -55 to<br>+150 | °C    |

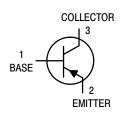
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.
- 2. Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.



## ON Semiconductor®

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#### MARKING DIAGRAM



SOT-723 CASE 631AA STYLE 1



3B = Specific Device Code M = Date Code

#### **ORDERING INFORMATION**

| Device         | Package              | Shipping <sup>†</sup> |
|----------------|----------------------|-----------------------|
| BC856BM3T5G    | SOT-723<br>(Pb-Free) | 8000 / Tape &<br>Reel |
| NSVBC856BM3T5G | SOT-723<br>(Pb-Free) | 8000 / Tape &<br>Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

| Characteristic  | Symbol               | Min       | Тур          | Max            | Unit     |
|---|----------------------|-----------|--------------|----------------|----------|
| OFF CHARACTERISTICS   | •                    |           | •            |                |          |
| Collector – Emitter Breakdown Voltage (I <sub>C</sub> = -10 mA)   | V <sub>(BR)CEO</sub> | -65       | -            | _              | V        |
| Collector – Emitter Breakdown Voltage ( $I_C = -10 \mu A, V_{EB} = 0$ )   | V <sub>(BR)CES</sub> | -80       | -            | -              | V        |
| Collector – Base Breakdown Voltage ( $I_C = -10 \mu A$ )  | V <sub>(BR)CBO</sub> | -80       | -            | -              | V        |
| Emitter – Base Breakdown Voltage $(I_E = -1.0 \mu A)$   | V <sub>(BR)EBO</sub> | -5.0      | -            | -              | V        |
| Collector Cutoff Current $(V_{CB} = -30 \text{ V})$<br>$(V_{CB} = -30 \text{ V}, T_A = 150^{\circ}\text{C})$                              | Ісво                 | -<br>-    | -<br>-       | -15<br>-4.0    | nA<br>μA |
| ON CHARACTERISTICS  |                      |           |              |                |          |
| DC Current Gain   | h <sub>FE</sub>      | -<br>220  | 150<br>290   | -<br>475       | -        |
| Collector – Emitter Saturation Voltage ( $I_C = -10$ mA, $I_B = -0.5$ mA) ( $I_C = -100$ mA, $I_B = -5.0$ mA)                             | V <sub>CE(sat)</sub> | -<br>-    | -<br>-       | -0.3<br>-0.65  | V        |
| Base – Emitter Saturation Voltage ( $I_C = -10$ mA, $I_B = -0.5$ mA) ( $I_C = -100$ mA, $I_B = -5.0$ mA)                                  | V <sub>BE(sat)</sub> | -<br>-    | -0.7<br>-0.9 | -              | V        |
| Base – Emitter Voltage ( $I_C = -2.0$ mA, $V_{CE} = -5.0$ V) ( $I_C = -10$ mA, $V_{CE} = -5.0$ V)   | V <sub>BE(on)</sub>  | -0.6<br>- | -<br>-       | -0.75<br>-0.82 | mV       |
| SMALL-SIGNAL CHARACTERISTICS  |                      |           |              |                |          |
| Current – Gain – Bandwidth Product $(I_C = -10 \text{ mA}, V_{CE} = -5.0 \text{ Vdc}, f = 100 \text{ MHz})$                               | f <sub>T</sub>       | 100       | _            | -              | MHz      |
| Output Capacitance<br>(V <sub>CB</sub> = -10 V, f = 1.0 MHz)  | C <sub>obo</sub>     | -         | _            | 4.5            | pF       |
| Noise Figure (I <sub>C</sub> = $-0.2$ mA, V <sub>CE</sub> = $-5.0$ Vdc, R <sub>S</sub> = $2.0$ k $\Omega$ , f = $1.0$ kHz, BW = $200$ Hz) | NF                   | -         | -            | 10             | dB       |

#### **TYPICAL CHARACTERISTICS**

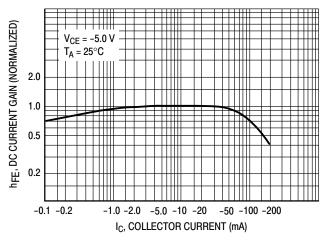


Figure 1. DC Current Gain

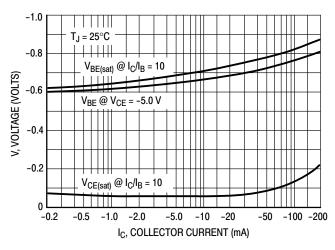


Figure 2. "On" Voltage

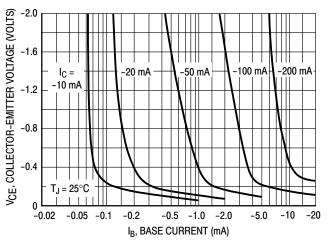


Figure 3. Collector Saturation Region

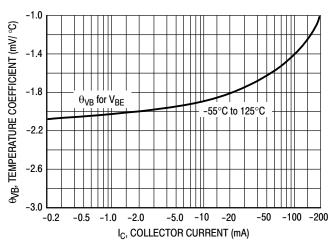


Figure 4. Base-Emitter Temperature Coefficient

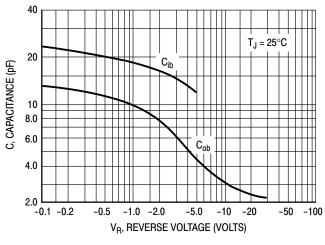


Figure 5. Capacitance

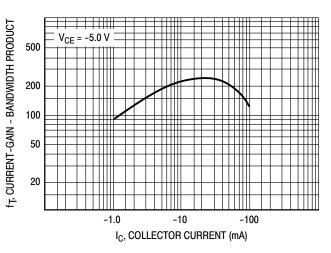
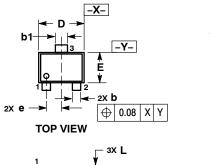
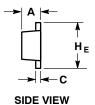


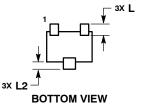
Figure 6. Current-Gain - Bandwidth Product

#### PACKAGE DIMENSIONS

#### SOT-723 CASE 631AA ISSUE D







STYLE 1: PIN 1. BASE 2. EMITTER 3. COLLECTOR

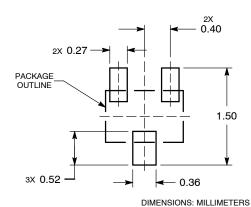
#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME
- Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

  DIMENSIONS D AND E DO NOT INCLUDE MOLD
- FLASH, PROTRUSIONS OR GATE BURRS.

|     | MILLIMETERS |      |      |  |
|-----|-------------|------|------|--|
| DIM | MIN         | NOM  | MAX  |  |
| Α   | 0.45        | 0.50 | 0.55 |  |
| b   | 0.15        | 0.21 | 0.27 |  |
| b1  | 0.25        | 0.31 | 0.37 |  |
| С   | 0.07        | 0.12 | 0.17 |  |
| D   | 1.15        | 1.20 | 1.25 |  |
| Е   | 0.75        | 0.80 | 0.85 |  |
| е   | 0.40 BSC    |      |      |  |
| ΗE  | 1.15        | 1.20 | 1.25 |  |
| L   | 0.29 REF    |      |      |  |
| L2  | 0.15        | 0.20 | 0.25 |  |

#### RECOMMENDED **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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